

Features

- 1.2kV Schottky Rectifier
- Zero Reverse Recovery Current
- High-Frequency Operation
- Temperature-Independent Switching
- Extremely Fast Switching
- Positive Temperature Coefficient on V_E

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies (SMPS)
- Boost diodes in PFC or DC/DC stages
- Free Wheeling Diodes in Inverter stages
- AC/DC converters

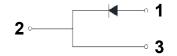




Maximum Ratings (T_c=25°C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
V _{RRM}	Repetitive Peak Reverse Voltage	1200	٧		
V _{RSM}	Surge Peak Reverse Voltage	1300	٧		
V _R	DC Peak Reverse Voltage	1200	٧		
I _F	Continuous Forward Current	33 16 10	А	T _c =25°C T _c =135°C T _c =156°C	Fig. 3
I _{FRM}	Repetitive Peak Forward Surge Current	47 31.5	А	T_c =25°C, t_p =10 ms, Half Sine Pulse T_c =110°C, t_p =10 ms, Half Sine Pulse	
I _{FSM}	Non-Repetitive Forward Surge Current	71 59.5	А	T_c =25°C, t_p =10 ms, Half Sine Pulse T_c =110°C, t_p =10 ms, Half Sine Pulse	Fig. 8
I _{F,Max}	Non-Repetitive Peak Forward Current	750 620	А	T_c =25°C, t_p =10 ms, Pulse T_c =110°C, t_p =10 ms, Pulse	Fig. 8
P _{tot}	Power Dissipation	166.5 72	W	T _c =25°C T _c =110°C	Fig. 4
dV/dt	Diode dV/dt ruggedness	200	V/ns	V _R =0-960V	
∫i²dt	i²t value	25 17.5	A²s	T _c =25°C, t _p =10 ms T _c =110°C, t _p =10 ms	
T _J	Operating Junction Range	-55 to +175	°C		
T _{stg}	Storage Temperature Range	-55 to +135	°C		
	TO-220 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	







Electrical Characteristics

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V _F	Forward Voltage	1.5 2.2	1.8 3	V	I _F = 10 A T _J =25°C I _F = 10 A T _J =175°C	Fig. 1
I _R	Reverse Current	30 55	250 350	μA	V _R = 1200 V T _J =25°C V _R = 1200 V T _J =175°C	Fig. 2
Q _c	Total Capacitive Charge	52		nC	$V_R = 800 \text{ V}, I_F = 10\text{A}$ $di/dt = 200 \text{ A}/\mu\text{s}$ $T_J = 25^{\circ}\text{C}$	Fig. 5
С	Total Capacitance	754 45 38		pF	V _R = 0 V, T _J = 25°C, f = 1 MHz V _R = 400 V, T _J = 25°C, f = 1 MHz V _R = 800 V, T _J = 25°C, f = 1 MHz	Fig. 6
E _c	Capacitance Stored Energy	14.5		μJ	V _R = 800 V	Fig. 7

Note: This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

Symbol	Parameter	Тур.	Unit	Note
$R_{\theta JC}$	Thermal Resistance from Junction to Case	0.9	°C/W	Fig. 9

Typical Performance

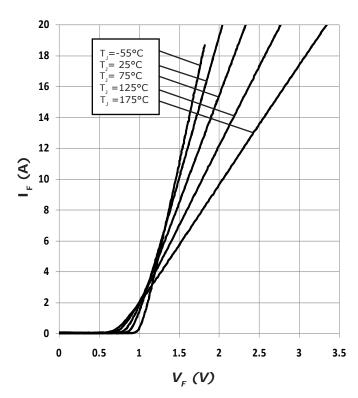


Figure 1. Forward Characteristics

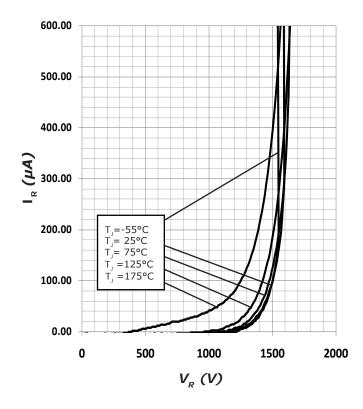
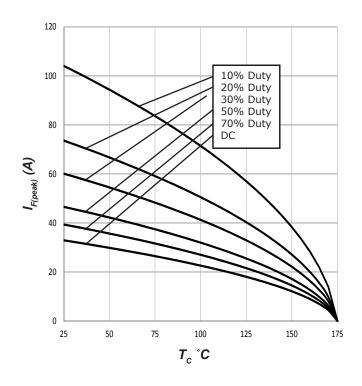


Figure 2. Reverse Characteristics

Typical Performance



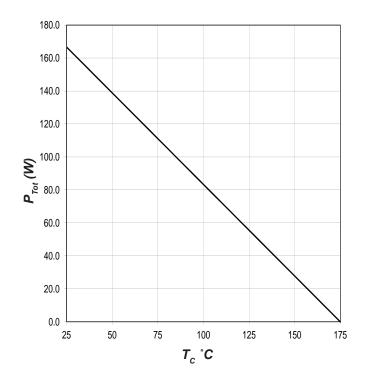


Figure 3. Current Derating

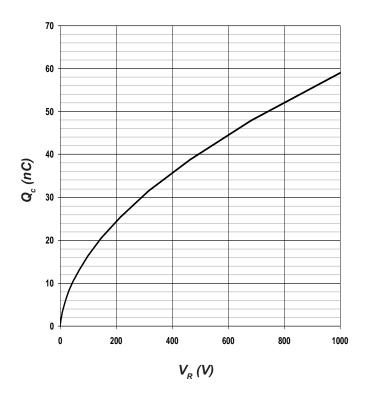


Figure 4. Power Derating

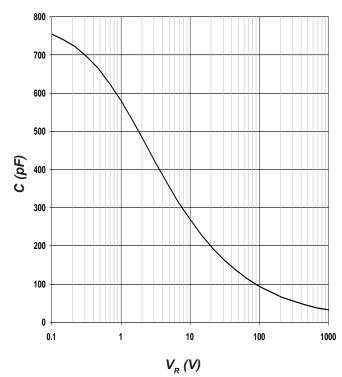
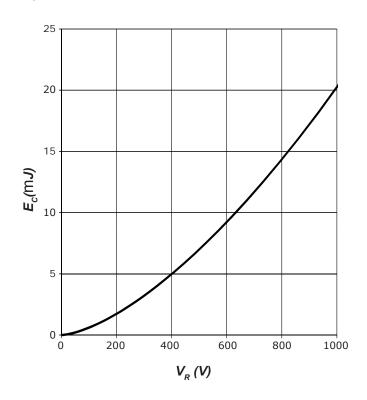


Figure 5. Recovery Charge vs. Reverse Voltage

Figure 6. Capacitance vs. Reverse Voltage



Typical Performance



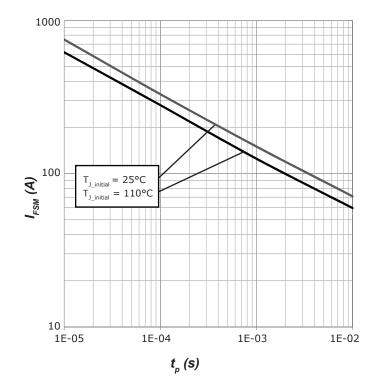


Figure 7. Typical Capacitance Stored Energy

Figure 8. Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

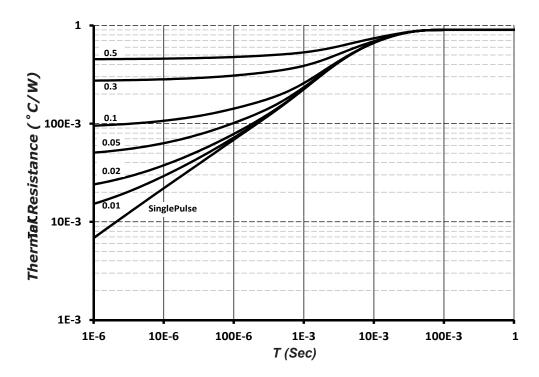


Figure 9. Transient Thermal Impedance

Diode Model

$$\begin{array}{c|c} - & & \\ \hline - & & \\ - & & \\ \hline - & & \\ - & & \\ \hline - & & \\ - & & \\ \hline - & & \\ - & & \\ \hline - & & \\ - & & \\ \hline - & & \\ - & & \\ \hline - & & \\ - & & \\ \hline - & & \\ - & & \\ \hline - & & \\ - & & \\ \hline - & &$$

$$V_{fT} = V_T + If^*R_T$$

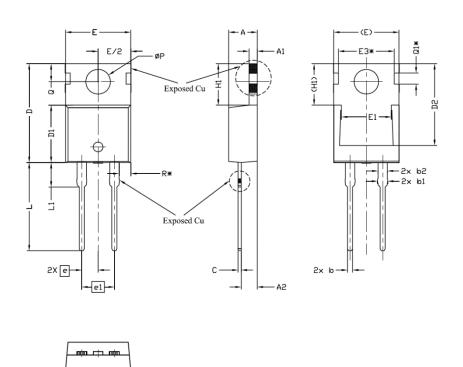
$$V_T = 0.98 + (T_J^* - 1.71^*10^{-3})$$

 $R_T = 0.040 + (T_J^* 5.32^*10^{-4})$

Note: T_j = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

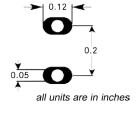


Package Information TO-220C-2L

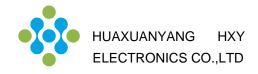


SYMBOL	MIN.	NOM.	MAX.	NOTES
Α	4,24	4,44	4,64	
A1	1.15	1.27	1.40	
A2	2.30	2.48	2.70	
Ф	0.70	0.80	0.90	
b1	1.20	1.55	1.75	
b2	1.20	1.45	1.70	
С	0.40	0.50	0.60	
D	14.70	15.37	16.00	4
D1	8.82	8.92	9.02	
D2	12.43	12.73	12.83	5
ш	9.96	10.16	10.36	4,5
E1	6,86	7.77	8,89	5
E3*	E3* 8.70REF.			
e				
e1	5.08BSC			
H1	6.30	6.45	6.60	5,6
L	13.47	13.72	13.97	
L1	3.60	3.80	4.00	
ØP	3.75	3.84	3.93	
Q	2.60 2.80		3,00	
Q1*	1.73REF.			
R*				

Recommended Solder Pad Layout



TO-220C-2L



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